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Inclosure Material:

Metal

**Overall Length:** 

0.945 inches

# **Overall Height:**

0.252 inches

**Overall Width:** 

0.413 inches

# Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

#### **Mounting Method:**

Unthreaded hole

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

65.0 collector to base voltage/static/emitter open and 65.0 collector to emitter reverse voltage and 3.5 emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

15.00 amperes source cutoff current

### Power Rating Per Characteristic:

535.0 watts small-signal input power, common-collector absolute

#### Transfer Ratio:

30.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: npn

# **Nuclear Hardness Critical Feature:**

Hardened

#### **Terminal Type And Quantity:**

1 tab, solder lug and 1 case

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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